



NPN/PNP EPITAXIAL PLANAR SILICON TRANSISTORS

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NPN CSC3198 PNP CSA1266

TO-92

TO-92 Plastic Package RoHS compliant

APPLICATION: General Purpose Switching Application

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C Unless otherwise specified)

PARAMETER	SYMBOL	VALUE	UNIT
Collector Base Voltage	V_{CBO}	50	V
Collector Emitter Voltage	V_{CEO}	50	V
Emitter Base Voltage	V_{EBO}	5	V
Collector Current	I _C	150	mA
Base Current	l _B	50	mA
Collector Power Dissipation	PC	625	mW
Operating And Storage Junction Temperature Range	T_{j},T_{stg}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	VALUE			UNIT
PARAMETER	STIMBOL TEST CONDITION		MIN	TYP	MAX	ONIT
Collector Cut Off Current	I _{CBO}	$V_{CB} = 50V$, $I_{E} = 0$			100	nA
Emitter Cut Off Current	I _{EBO}	V_{EB} =5 V , I_{C} = 0			100	nA
DC Current Gain	h _{FE} ¹	$I_C = 2mA, V_{CE} = 6V$	70		400	
DC Current Gain	h _{FE}	$I_C = 150 \text{mA}, V_{CE} = 6V$	25			
Collector Emitter Saturation Voltage	$V_{CE(sat)}$	I_C =100mA, I_B = 10mA			0.30	V
Base Emitter Saturation Voltage	V _{BE(sat)}	I_C =100mA, I_B = 10mA			1.1	V

DYNAMIC CHARACTERISTICS

Transition Frequency	f _T	V _{CE} =10V, I _C =1mA	80			MHz
Collector Output Capacitance	C_ob	V _{CB} =10V,I _E =0, f=1MHz			7.0	pF
Base Intrinsic Resistance	rbb'	V_{CB} =10V, I_{E} =1mA, f=30MHz		30		Ω
Noise Figure	NF	V_{CE} =6V, I_{C} =0.1mA, R_{g} =10KW , f =1KHz			10	dB

Note:

CLASSIFICATION	0	Υ	GR
1. hFE	70-140	120-240	200-400

Note: For PNP type device Voltage and Current values are negative (-).

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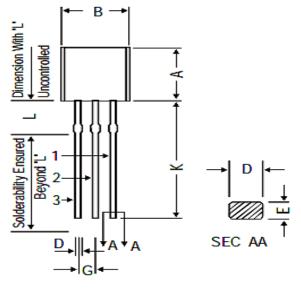




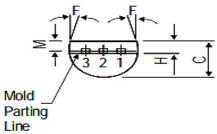


PACKAGE DETAILS

TO-92 Plastic Package



MIN.	MAX.	
4.32 5.33		
4.45	5.20	
3.18	4.19	
0.41	0.55	
0.35	0.50	
5	0	
1.14	1.40	
1.20	1.40	
12.70	-	
1.982	2.082	
1.03	1.20	
	4.32 4.45 3.18 0.41 0.35 5 1.14 1.20 12.70 1.982	



All dimensions are in mm

PIN CONFIGURATION

- 1. BASE
- 2. COLLECTOR
- 3. EMITTER



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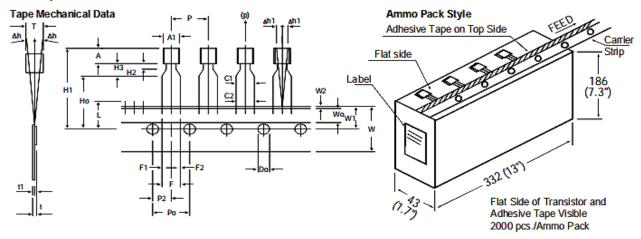
Continental Device India Pvt. Limited

An IATF 16949, ISO9001 and ISO 14001 Certified Company





TO-92 Tape and Ammo Pack



All dimensions are in mm

		SPECIFICATION				
ПЕМ	SYMBOL	MIN.	NOM.	MAX.	TOL.	
BODY WIDTH	A1	4.0		4.8		
BODY HEIGHT	Α	4.8		5.2		
BODY THICKNESS	T	3.9		4.2		
PITCH OF COMPONENT	P		12.7		± 1.0	
*1 FEED HOLE PITCH	Po		12.7		± 0.3	
*2 FEED HOLE CENTRE TO COMPONENT CENTRE	P2		6.35		± 0.4	
DISTANCE BETWEEN OUTER LEADS	F		5.08		+ 0.6	
*3 COMPONENT ALIGNMENT SIDE VIEW	Δh		0	1.0		
*4 COMPONENT ALIGNMENT FRONT VIEW	∆h1		0	1.3		
TAPE WIDTH	w		18		± 0.5	
HOLD-DOWN TAPE WIDTH	Wo		6		± 0.2	
HOLE POSITION	W1		9		+ 0.7	
					- 0.5	
HOLD-DOWN TAPE POSITION	W2		0.5		± 0.2	
LEAD WIRE CLINCH HEIGHT	Ho		16		± 0.5	
COMPONENT HEIGHT	H1			23.25		
LENGTH OF SNIPPED LEADS	L			11.0		
FEED HOLE DIAMETER	Do		4		± 0.2	
*5 TOTAL TAPE THICKNESS	t			1.2		
LEAD - TO - LEAD DISTANCE	F1, F2		2.54		+ 0.4 - 0.1	
STAND OFF	H2	0.45		1.45		
CLINCH HEIGHT	H3			3.0		
LEAD PARALLELISM	C1-C2			0.22		
PULL - OUT FORCE	(p)	6N				

NOTES

- 1. Maximum alignment deviation between leads will not to be greater than 0.2mm.
- 2. Maximum non-cumulative variation between tape feed holes shall not exceed 1 mm in 20 pitches.
- 3. Holddown tape will not exceed beyond the edge(s) of carrier tape and there shall be no exposure of adhesive.
- 4. There will be no more than three (3) consecutive missing components in a tape.
- 5. A tape trailer, having at least three feed holes are provided after the last component in a tape.
- 6. Splices should not interfere with the sprocket feed holes.

REMARKS

- 1. Cumulative pitch error 1.0 mm/20 pitch
- 2. To be measured at bottom of clinch
- 3. At top of body
- 4. At top of body
- 5. t1 0.3 0.6 mm

Packing Details

PACKAGE	STAND	STANDARD PACK		INNER CARTON BOX		CARTON BOX	
	Details	Net Weight/Qty	Size	Qty	Size	Qty	GrWt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3' x 7.5" x 7.5"	5K	17' x 15' x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	125"x8"x1.8"	2K	17' x 15' x 13.5"	32K	12.5 kgs

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Recommended Product Storage Environment for Discrete Semiconductor Devices

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- · Temperature 5 °C to 30 °C
- · Humidity between 40 to 70 %RH
- · Air should be clean.
- Avoid harmful gas or dust.
- · Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- · Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- · Avoid rapid change of temperature.
- · Avoid condensation.
- · Mechanical stress such as vibration and impact shall be avoided.
- · The product shall not be placed directly on the floor.
- $\cdot\,$ The product shall be stored on a plane area. They should not be turned upside down.

They should not be placed against the wall.

Shelf Life of CDIL Products

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start.

For this, the following JEDEC table may be referred:

JEDEC MSL Level					
Level	Time	Condition			
1	Unlimited	≤30 °C / 85% RH			
2	1 Year	≤30 °C / 60% RH			
2a	4 Weeks	≤30 °C / 60% RH			
3	168 Hours	≤30 °C / 60% RH			
4	72 Hours	≤30 °C / 60% RH			
5	48 Hours	≤30 °C / 60% RH			
5a	24 Hours	≤30 °C / 60% RH			
6	Time on Label(TOL)	≤30 °C / 60% RH			

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Customer Notes

Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



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